

Taehwan Jun

List of Publications by Year in descending order

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Version: 2024-02-01

10
papers

1,187
citations

1040056

9
h-index

1474206

9
g-index

10
all docs

10
docs citations

10
times ranked

1862
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|---|------|-----------|
| 1 | Performance boosting strategy for perovskite light-emitting diodes. Applied Physics Reviews, 2019, 6, 031402. | 11.3 | 88 |
| 2 | One-step solution synthesis of white-light-emitting films via dimensionality control of the Cs ⁺ Cu ⁺ I system. APL Materials, 2019, 7, . | 5.1 | 73 |
| 3 | Lead-free Highly Efficient Blue-emitting Cs ₃ Cu ₂ I ₅ with OD Electronic Structure. Advanced Materials, 2018, 30, e1804547. | 21.0 | 477 |
| 4 | Bias stress stable aqueous solution derived Y-doped ZnO thin film transistors. Journal of Materials Chemistry, 2011, 21, 13524. | 6.7 | 55 |
| 5 | High-performance low-temperature solution-processable ZnO thin film transistors by microwave-assisted annealing. Journal of Materials Chemistry, 2011, 21, 1102-1108. | 6.7 | 163 |
| 6 | Influences of pH and Ligand Type on the Performance of Inorganic Aqueous Precursor-Derived ZnO Thin Film Transistors. ACS Applied Materials & Interfaces, 2011, 3, 774-781. | 8.0 | 33 |
| 7 | Low-temperature soluble InZnO thin film transistors by microwave annealing. Journal of Crystal Growth, 2011, 326, 23-27. | 1.5 | 44 |
| 8 | Fully Flexible Solution-deposited ZnO Thin-film Transistors. Advanced Materials, 2010, 22, 4308-4312. | 21.0 | 166 |
| 9 | Flexible Electronics: Fully Flexible Solution-Deposited ZnO Thin-Film Transistors (Adv. Mater. 38/2010). Advanced Materials, 2010, 22, n/a-n/a. | 21.0 | 0 |
| 10 | Low Temperature Solution-Processed InZnO Thin-Film Transistors. Journal of the Electrochemical Society, 2010, 157, J111. | 2.9 | 88 |